

10/728, 519.

COPY



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**Applicant: Stephen W. Bedell, et al.**

**Docket: 17107**

**Patent No.: 6,972,247 B2**

**Dated: April 20, 2006**

**Issued: December 06, 2005**

**For: METHOD OF FABRICATING STRAINED  
SI SOI WAFERS**

**Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450**

**Certificate  
APR 27 2006  
of Correction**

**REQUEST FOR CERTIFICATE OF CORRECTION**

**Sir:**

**It appears that errors have been introduced in the  
course of printing the Patent issued in the above application, and it is  
respectfully requested that the Commissioner issue a Certificate of  
Correction in the following respects:**

**Column 9, Line 56, Claim 14:**

**"3E16 cm<sup>-1</sup>." should read -- 3E16 cm<sup>-2</sup>. --**

**Column 10, Line 3, Claim 19:**

**"process of a spike anneal." should read -- process or a spike  
anneal --**

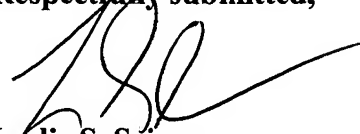
**Column 10, Line 16, Claim 23:**

**"process of a spike anneal" should read -- process or a spike  
anneal --**

**Column 12, Line 32, Claim 53:**

**“from about to about 500 nm” should read – from about 10 to about 500 nm --**

**Respectfully submitted,**

A handwritten signature in black ink, appearing to read 'LSZ', with a long horizontal flourish extending to the right.

**Leslie S. Szivos  
Reg. No. 39,394**

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**UNITED STATES PATENT AND TRADEMARK OFFICE  
CERTIFICATE OF CORRECTION**

PATENT NO : 6,972,247 *B2*  
APPLICATION NO : 10/728,519  
ISSUE DATE : December 06, 2005  
INVENTOR(S) : Stephen W. Bedell, et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 9, Line 56, Claim 14:  
"3E16 cm<sup>-1</sup>." should read -- 3E16 cm<sup>-2</sup>. --

Column 10, Line 3, Claim 19:  
"process of a spike anneal." should read -- process or a spike anneal --

Column 10, Line 16, Claim 23:  
"process of a spike anneal" should read -- process or a spike anneal --

Column 12, Line 32, Claim 53:  
"from about to about 500 nm" should read -- from about 10 to about 500 nm --

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PATENT No. 6,972,247 *B2*

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